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#### ZXTP56020FDBQ

#### 20V DUAL PNP LOW V<sub>CE(SAT)</sub> TRANSISTOR

#### **Features**

- BV<sub>CEO</sub> > -20V
- I<sub>C</sub> = -2A High Continuous Collector Current
- $R_{CE(SAT)} = 100 m\Omega$  for a Low Equivalent On-Resistance
- Low Saturation Voltage V<sub>CE(SAT)</sub> < -150mV @ -1A</li>
- Sidewall Tin Plating for Wettable Flanks in AOI
- P<sub>D</sub> up to 2.47W for Power Demanding Applications
- Low Profile 0.6mm High Package for Thin Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

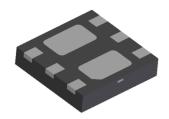
# Mechanical Data

- Case: U-DFN2020-6 (SWP) (Type A) with Sidewall Plating (SWP)
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin, Solderable per MIL-STD-202, Method 208 <sup>®</sup>
- Weight: 0.0065 grams (Approximate)

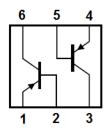
### **Application**

- Matrix LED Lighting
- Power Management

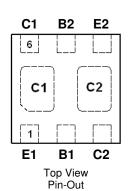
#### U-DFN2020-6 (SWP) (Type A)



**Bottom View** 



Device Symbol



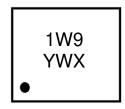
#### Ordering Information (Notes 4 & 5)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXTP56020FDBQ-7	1W9	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product\_compliance\_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



1W9 = Product Type Marking Code Y = Year: 0~9

W = Week: A~Z: 1~26 week; a~z; 27~52 week; z represents

52 and 53 week X = A~Z: Internal Code



## Absolute Maximum Ratings - Q1 & Q2 (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-20	V
Collector-Emitter Voltage	$V_{\sf CEO}$	-20	V
Emitter-Base Voltage	$V_{EBO}$	-7	V
Continuous Collector Current	lc	-2	Α
Peak Pulse Collector Current	Ісм	-3	A
Base Current	I <sub>B</sub>	-300	mA
Peak Base Current	Івм	-1	Α

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
	(Notes 6 & 8)		405	mW	
Power Dissipation	(Notes 6 & 9)	Ъ	510		
rower dissipation	(Notes 7 & 8)	$P_{D}$	1650	IIIVV	
	(Notes 7 & 9)		2470	Ì	
	(Notes 6 & 8)		308	°C/W	
nermal Resistance, Junction to Ambient	(Notes 6 & 9)		245		
	(Notes 7 & 8)	$R_{\theta JA}$	76	°C/ <b>VV</b>	
	(Notes 7 & 9)		51		
Thermal Resistance, Junction to Lead	(Note 10)	$R_{ heta JL}$	18	°C/W	
Operating and Storage Temperature Range	_	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

## ESD Ratings (Note 11)

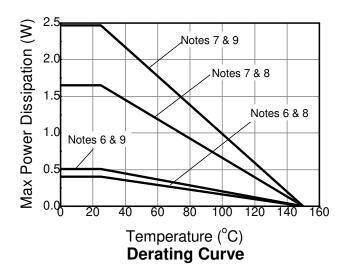
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

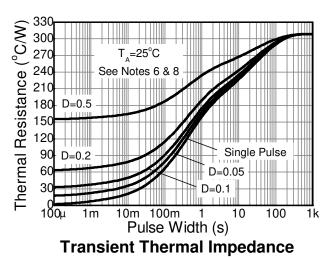
Notes:

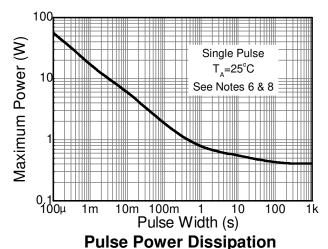
- 6. For a device mounted with the exposed collector pads on minimum recommended pad layout that is on a single-sided 1.6mm FR-4 PCB; device is For a device mounted with the exposed collector pads on minimum recommended pad layout that is on a sing measured under still air conditions whilst operating in a steady-state.
  Same as note (6), except the device is mounted with the collector pad on 28mm x 28mm (8cm²) 2oz copper.
  For a dual device with one active die.
  For dual device with 2 active die running at equal power.
  Thermal resistance from junction to solder-point (on the exposed collector pads).
  Refer to JEDEC specification JESD22-A114 and JESD22-A115.

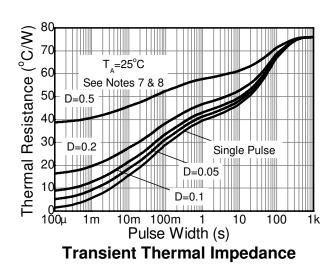


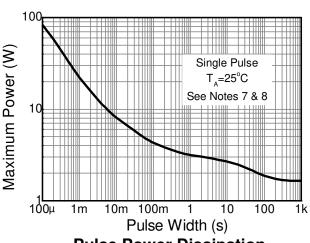
# **Thermal Characteristics and Derating Information**













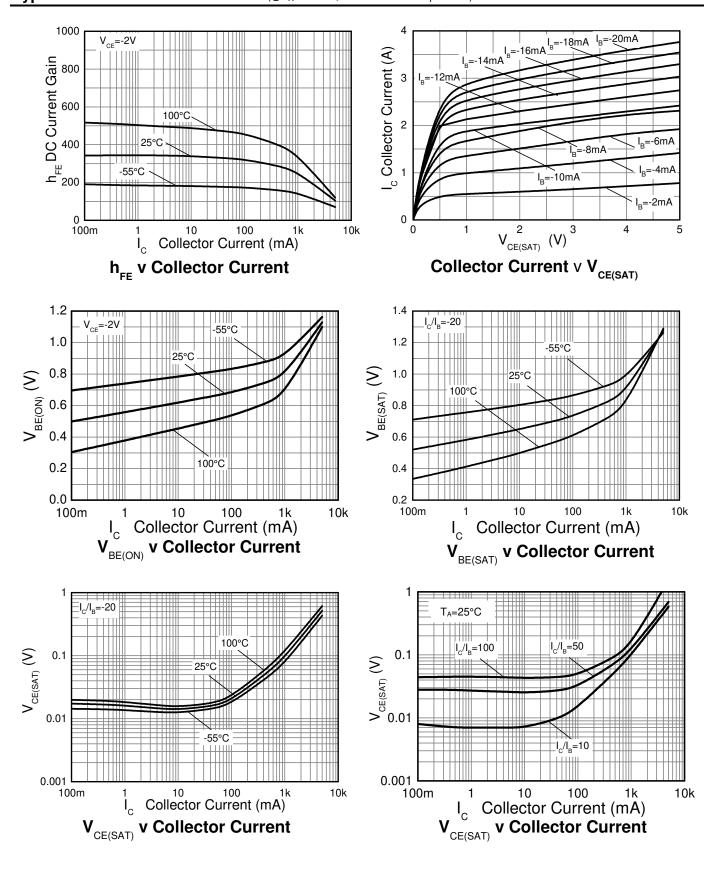
# **Electrical Characteristics – Q1 & Q2** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-20	_	_	V	$I_C = -100\mu A$
Collector-Emitter Breakdown Voltage (Note 12)	BV <sub>CEO</sub>	-20	_	_	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	_	_	V	$I_E = -100\mu A$
Collector-Base Cutoff Current	lone	_	_	-100	nA	$V_{CB} = -16V, I_{E} = 0$
	Ісво		_	-50	μΑ	$V_{CB} = -16V, I_E = 0, T_A = +150$ °C
Emitter-Base Cutoff Current	I <sub>EBO</sub>		_	-100	nA	$V_{EB} = -5.6V, I_{C} = 0$
		250	_	_		$V_{CE} = -2V, I_{C} = -100mA$
		210	_	_		$V_{CE} = -2V, I_{C} = -500mA$
DC Current Gain (Note 12)	h <sub>FE</sub>	170	_	_	_	$V_{CE} = -2V, I_{C} = -700mA$
		160	_	_		$V_{CE} = -2V, I_{C} = -1A$
		100	_	_		$V_{CE} = -2V, I_{C} = -2A$
	V <sub>CE</sub> (SAT)		_	-110		$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
			_	-220	mV	$I_C = -1A$ , $I_B = -50mA$
Collector-Emitter Saturation Voltage (Note 12)			_	-200		$I_C = -0.7A$ , $I_B = -7mA$
		_	_	-390		$I_C = -2A$ , $I_B = -200mA$
Equivalent On-Resistance (Note 12)	R <sub>CE(SAT)</sub>	_	_	220	mΩ	$I_E = -1A$ , $I_B = -50mA$
	V <sub>BE(SAT)</sub>	_	_	-1	V	$I_C = -0.5A$ , $I_B = -50mA$
Base-Emitter Saturation Voltage (Note 12)		_	_	-1.1		$I_C = -1A$ , $I_B = -50mA$
			_	-1.25		I <sub>C</sub> = -2A, I <sub>B</sub> = -200mA
Base-Emitter Turn-on Voltage (Note 12)	V <sub>BE(ON)</sub>		_	-0.9	V	$V_{CE} = -2V, I_{C} = -0.5A$
Turn-On Time	ton		60	_	ns	
Delay Time	t <sub>D</sub>		10		ns	$I_{C} = -1A$ , $I_{B1} = -I_{B2} = 50$ mA;
Rise Time		_	50		ns	$T_A = +25$ °C

Note: 12. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s$ . Duty cycle  $\leq 2\%$ .



## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

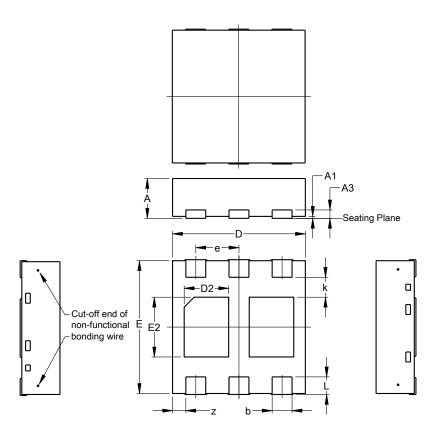




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2020-6 (SWP) (Type A)

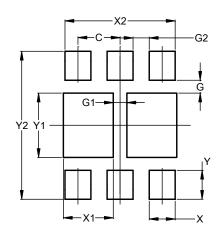


U-DFN2020-6 (SWP)					
(Type A) ´					
Dim	Min	Max	Тур		
Α	0.55	0.65	0.60		
A1	0.00	0.05	0.03		
A3			0.127		
b	0.25	0.35	0.30		
D	1.95	2.05	2.00		
D2	0.57	0.77	0.67		
Е	1.95	2.05	2.00		
E2	0.80	1.00	0.90		
е	0.65BSC				
k	0.30BSC				
L	0.22	0.32	0.27		
Z	0.20BSC				
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2020-6 (SWP) (Type A)



Dimensions	Value
Difficitsions	(in mm)
С	0.650
G	0.200
G1	0.210
G2	0.250
X	0.400
X1	0.770
X2	1.700
Υ	0.450
Y1	1.000
Y2	2.300



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